# Dr. Babasaheb Ambedkar Technological University

Course Structure and Syllabus For M. Tech. (VLSI) Two Year (Four Semester) Course (w.e.f. July 2017)



DR. BABASAHEB AMBEDKAR TECHNOLOGICAL UNIVERSITY, Lonere-402103, Raigad (MS)

## M.Tech. (VLSI)

#### **Objectives**:

- I. To serve the society and nation, by providing high quality engineering educational programs to the students, engaging in research and innovations that will enhance the skill and knowledge and assisting the economic development of the region, state, and nation through technology transfer.
- II. To equip the postgraduate students with the state of the art education through research and collaborative work experience/culture to enable successful, innovative, and life-long careers in Electronics and Telecommunication.
- III. To encourage the post-graduates students, to acquire the academic excellence and skills necessary to work as Electronics and Telecommunication professional in a modern, ever-evolving world.
- IV. To provide the broad understanding of social, ethical and professional issues of contemporary engineering practice and related technologies, as well as professional, ethical, and societal responsibilities.
- V. To inculcate the skills for perusing inventive concept to provide solutions to industrial, social or nation problem.

#### **Outcomes:**

- I. Students of this program will have ability to apply knowledge of mathematics, sciences and engineering to Electronics and Telecommunication problems.
- II. Postgraduate students will gain an ability to design and conduct experiments, as well as to analyze and interpret data/results.
- III. Learners of this program will built an ability to design and develop a system, components, devices, or process to meet desired needs.
- IV. Masters students of this program will have an ability to work on multidisciplinary teams and also as an individual for solving issues related to Electronics and Telecommunication.
- V. Learners of this program will have an ability to identify, formulate, and solve Engineering problems by applying mathematical foundations, algorithmic principles, and Electronics and Telecommunication theory in the modeling and design of electronics systems in a way that demonstrates comprehension of the tradeoffs involved in design choices.
- VI. Postgraduate students will have an ability to communicate effectively orally and in writing and also understanding of professional and ethical responsibility.
- VII. Postgraduate students will have an ability to use the techniques, skills, and modern engineering EDA tools necessary for Electronics and Telecommunication practices.
- VIII. Learners of this program will have an ability to evaluate Electronics and Telecommunication Engineering problems with cost effectiveness, features, and user friendliness to cater needs for innovative product development.
- IX. Postgraduate students will have an ability to solve contemporary social and industrial problems by engaging in life-long learning.

# Dr. Babasaheb Ambedkar Technological University

Teaching and Examination Scheme for

M.Tech. (VLSI) w.e.f. July 2017

\$\black\$ CodeName of the courseIIITTTII		G					Examination scheme						
2         I         V         III         Test         V         III         Test         V         IIII         Test         V         IIIII         Test         V         IIIIIIIIIIIIIIIIIIIIIIIIIIIIIIIIIIII	ir. No.	Course Code	Name of the course	Hou	irs/ W	eek	Credit	The	ory	IA	PR/OR	TOTAL	
NTVLC101         Graph Theory and Discrete Optimization         03          1         04         60         20         20          100           03         MTVLC102         Analog IC Design         03          1         04         60         20         20          100           03         MTVLC103         Basics of VLS1         03          1         04         60         20         20          100           04         MTVLE125         Elective-1         03          03         60         20         20          100           05         MTVLE106         Communication Skills         03          03         60         20         20          100           06         MTVLC106         Communication Skills         03          10         03         60         20         20          100           01         MTVLC200         Design of ASICs         03          1         04         60         20         20          100           02         MTVL220         Design of ASICs         03	2			L P T			ТН	Test			-		
01         MTVLC101         Graph Theory and Discrete Optimization         03          1         04         60         20         20          100           02         MTVLC102         Analog IC Design         03          1         04         60         20         20          100           03         MTVLC103         Basics of VLSI         03          1         04         60         20         20          100           04         MTVL214         Elective-I         03          03         60         20         20          100           05         MTVL215         Elective-II         03          03         60         20         20          100           06         MTVL107         PG Lab-1*          03         03          10         04         60         20         20          100           07         MTVL201         VLS1 System Testing         03          1         04         60         20         20          100           03         MTVL223         Lective-III	First	Semester		<u>.</u>									
02 03 04 04 	01	MTVLC101	Graph Theory and Discrete Optimization	03		1	04	60	20	20		100	
03 04 04 07 07 08 07 08 0	02	MTVLC102	Analog IC Design	03		1	04	60	20	20		100	
04 05 07 0	03	MTVLC103	Basics of VLSI	03		1	04	60	20	20		100	
05 06 07 0	04	MTVLE114	Elective-I	03			03	60	20	20		100	
06 07 <td>05</td> <td>MTVLE125</td> <td>Elective-II</td> <td>03</td> <td></td> <td></td> <td>03</td> <td>60</td> <td>20</td> <td>20</td> <td></td> <td>100</td>	05	MTVLE125	Elective-II	03			03	60	20	20		100	
01MTVLL101 IPG Lab-I* IGTI03I02II <th< td=""><td>06</td><td>MTVLC106</td><td>Communication Skills</td><td>02</td><td></td><td></td><td>02</td><td></td><td></td><td>25</td><td>25</td><td>50</td></th<>	06	MTVLC106	Communication Skills	02			02			25	25	50	
Image: construct of the series of the ser	07	MTVLL107	PG Lab-I*		03		02			25	25	50	
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01         MTVLC201         VLSI System Testing         03          1         04         60         20         20          100           02         MTVLC202         Design of ASICs         03          1         04         60         20         20          100           03         MTVLC202         Design of ASICs         03          1         04         60         20         20          100           04         MTVLE233         Elective-III         03           03         60         20         20          100           05         MTVLE244         Elective-IV         03           03         60         20         20          100           06         MTVL2506         Seminar-I          04          02          50         50         100           07         MTVLP207         Mini-Project          04          02         10         100         200         100         100         100           1         MTVL201         Project Management &Intellectual Prop	Seco	nd Semeste	er										
02       MTVLC202       Design of ASICs       03        1       04       60       20       20        100         03       MTVL233       Elective-III       03        03       60       20       20        100         04       MTVL244       Elective-IV       03       03        03       60       20       20        100         05       MTVL255       Elective-V(Open to all)       03        04        03       60       20       20        100         06       MTVL206       Seminar-I        04        02         50       50       100         07       MTVL200       Mini-Project        04        02         50       50       100 <td>01</td> <td>MTVLC201</td> <td>VLSI System Testing</td> <td>03</td> <td></td> <td>1</td> <td>04</td> <td>60</td> <td>20</td> <td>20</td> <td></td> <td>100</td>	01	MTVLC201	VLSI System Testing	03		1	04	60	20	20		100	
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04 05 07 07 07 08 07 08 <td>03</td> <td>MTVLE233</td> <td>Elective-III</td> <td>03</td> <td></td> <td></td> <td>03</td> <td>60</td> <td>20</td> <td>20</td> <td></td> <td>100</td>	03	MTVLE233	Elective-III	03			03	60	20	20		100	
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06       MTVLS206       Seminar-I $$ $04$ $$ $02$ $$ $$ $50$ $50$ $100$ 07       MTVLP207       Mini-Project       Total for Semester $1$ $04$ $$ $02$ $$ $$ $50$ $50$ $100$ Thire-reserve         Image: Semester         1       MTVL2301       Project Management & Intellectual Property Rights (Self Study)# $$ $$ $$ $50$ $50$ $100$ 2       MTVLP302       Project-I $$ $ $	05	MTVLE255	Elective-V- (Open to all)	03			03	60	20	20		100	
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1       MTVLC301       Project Management &Intellectual Property Rights (Self Study)#         02         50       50       100         2       MTVLP302       Project-I         10         50       50       100         2       MTVLP302       Project-I         10         50       50       100         Fourth Semester         1         1       MTVLP401       Project-II         10         100       100       200         1         1       MTVLP401       Project-II         20         100       100       200         GRAND TOTAL         20         100       100       200	Thir	d Semester	•	<u>.</u>	- -								
2       ATVLP302       Rights (Self Study)# Project-I       1       1       1       1       1       50       50       100 <b>Fourier Semester III</b> 1       1       1       1       100       100       200         1         1       <	1	MTVLC301	Project Management &Intellectual Property				02			50	50	100	
2       MTVLP302       Project-I         10        50       50       100 <b>Total for Semester III</b> 12        100       100       200 <b>Fourth Semester</b> 1       MTVLP401       Project-II         20        100       100       200         1       MTVLP401       Project-II         20        100       100       200         1       MTVLP401       Project-II         20        100       100       200         1       MTVLP401       Project-II         20        100       100       200 <b>GRAND TOTAL</b>			Rights (Self Study)#										
Image: Constant of the second of th	2	MTVLP302	Project-I				10			50	50	100	
Fourth Semester         1       MTVLP401       Project-II         20        100       100       200         Image: Colspan="5">GRAND TOTAL			Total for Semester III			-	12			100	100	200	
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Total for Semester IV           20          100         100         200           GRAND TOTAL           100         100         200	1	MTVLP401	Project-II				20			100	100	200	
GRAND TOTAL 1700			Total for Semester IV				20			100	100	200	
	GRAND TOTAL 1700					1700							

\* PG Lab-I – Practical shall be based on courses of first semester.

# Student has to choose this course either from NPTEL/MOOC pool and submission of course completion certificate is mandatory.

## **Elective-I**

- A. Digital System Design
- B. Modeling and Synthesis with Verilog HDL
- C. Optimization of Digital Signal Processing structures for VLSI
- D. Cognitive Radio
- E. VLSI Process Technology

## **Elective-II**

- A. Advanced Computer Architecture
- B. Low Power VLSI circuits
- C. VLSI Digital Signal Processing Systems
- D. Advanced Digital Design
- E. RF circuits
- F. Mixed Signal Circuit Design

## **Elective-III**

- A. Functional Verification using Hardware Verification Languages
- B. High Speed System Design
- C. High Speed Communication Networks
- D. DSP Architecture
- E. RF MEMS

### **Elective-IV**

- A. Computer Aided Design for VLSI
- B. Semiconductor Memory Design and Testing
- C. FPGA System Design
- D. Nanoscale Devices and Circuit Design
- E. Analysis and Design of Digital Systems using VHDL

## Elective-V (Open)

- A. ASIC & SOC
- B. IC Technology
- C. Linear Algebra
- D. Research Methodology
- E. Internet of Things

## GRAPH THEORY AND DISCRETE OPTIMIZATION

Weekly T	eaching Hours	TH : 03	Tut: 01		
Scheme of Marking		TH :60	Tests : 20	IA: 20	Total : 100
Course Objective:					
А	To introduce the basi Optimization.	cs of graphs	and combinat	tory require	ed for VLSI design and

#### **Course Outcomes:**

CO1	Learner will be able to understand the various types of graph Algorithms and graph theory properties.
CO2	Learner will be able to analyze the NP – complete problems.
CO3	Learner will be able to distinguish the features of the various tree and matching algorithms
CO4	Learner will be able to understand applications of digraphs and graph flow.
CO5	Learner will be able to understand the linear programming principles and its conversion.

## <u>UNIT I</u>

Basic definitions, Degree of vertices, Complement of a graph. Self-complementary graph, some eccentricity properties of graphs. Tree, spanning tree. Directed graphs standard definitions; strongly, weakly, unilaterally connected digraphs, deadlock communication network. Matrix representation of graph and digraphs.

## <u>UNIT II</u>

Eulerian graphs and standard results relating to characterization. Hamiltonian graph-standard theorems (Dirac theorem, Chavathal theorem, closure of graph).Non Hamiltonian graph with maximum number of edges. Self-centered graphs and related simple theorems.

## <u>UNIT III</u>

Chromaticnumber; Vertex and edge (only properties and examples)-application to colouring. Planar graphs, Euler's formula, maximum number of edges in a planar graph. Five colour theorem. DFS-BFS algorithm, shortest path algorithm, min-spanning tree and max-spanning tree algorithm, planarity algorithm. Matching theory, maximal matching and algorithms form aximal matching. Perfect matching (only properties and applications to regular graphs).

## <u>UNIT IV</u>

Flows in graphs, Ranking of participants in tournaments, simple properties and theorems on strongly connected tournaments. Application of Eulerian digraphs. PERT-CPM. Complexity of algorithms; P-NP-NPC-NP hard problems and examples.

## <u>UNIT V</u>

Linear- Integer Linear programming, Conversion of TSP, maxflow, Knapsack scheduling, shortest path problems for Linear programming types - branch bound method to solve

## <u>UNIT VI</u>

Knapsack problems- critical path and linear programming conversion- Floor shop scheduling problem- Personal assignment problem.

Dynamic programming- TSP- compartment problems- Best investment problems.

- 1. C. Papadimitriou & K. Steiglitz, Combinatorial Optimization, Prentice Hall, 1982.
- 2. H. Gerez, Algorithms for VLSI Design Automation, John Wiley, 1999.
- 3. B. Korte&J. Vygen, Combinatorial Optimization, Springer- Verlag, 2000.
- 4. Recent literature in Graph Theory and Discrete Optimization.

## ANALOG IC DESIGN

Weekly Teaching Hours	TH : 03	Tut: 01		
Scheme of Marking	TH :60	Tests : 20	IA: 20	Total : 100

#### **Course Objective:**

А	To develop the ability design and analyze MOS based Analog VLSI circuits to draw the equivalent circuits of MOS based Analog VLSI and analyze their performance.
В	To develop the skills to design analog VLSI circuits for a given specification.

#### **Course Outcomes:**

CO1	Learner will be able to understand equivalent circuits of MOS based Analog VLSI and analyze their performance.
CO2	Learner will be able to design analog VLSI circuits for a given specification.
CO3	Learner will be able to analyze the frequency response of the different configurations of an amplifier.
CO4	Learner will be able to understand the feedback topologies involved in the amplifier design.
CO5	Learner will be able to design features of the differential amplifiers.

## <u>UNIT I</u>

Basic MOS Device Physics – General Considerations, MOS I/V Characteristics, Second Order effects, MOS Device models. Short Channel Effects and Device Models. Single Stage Amplifiers – Basic Concepts, Common Source Stage, Source Follower, Common Gate Stage, Cascode Stage.

## <u>UNIT II</u>

Differential Amplifiers – Single Ended and Differential Operation, Basic Differential Pair, Common-Mode Response, Differential Pair with MOS loads, Gilbert Cell. Passive and Active Current Mirrors – Basic Current Mirrors, Cascode Current Mirrors, Active Current Mirrors.

## <u>UNIT III</u>

Frequency Response of Amplifiers – General Considerations, Common Source Stage, Source Followers, Common Gate Stage, Cascode Stage, Differential Pair. Noise – Types of Noise, Representation of Noise in circuits, Noise in single stage amplifiers, Noise in Differential Pairs.

## <u>UNIT IV</u>

Feedback Amplifiers – General Considerations, Feedback Topologies, Effect of Loading.

## <u>UNIT V</u>

Operational Amplifiers – General Considerations, One Stage Op Amps, Two Stage Op Amps, Gain Boosting, Common – Mode Feedback, Input Range limitations, Slew Rate, Power Supply Rejection, Noise in Op Amps. Stability and Frequency Compensation.

## <u>UNIT VI</u>

Bandgap References, Introduction to Switched Capacitor Circuits, Nonlinearity and Mismatch.

- 1. B.Razavi, Design of Analog CMOS Integrated Circuits, McGraw Hill Edition 2002.
- 2. Paul. R.Gray, Robert G. Meyer, Analysis and Design of Analog Integrated Circuits, Wiley, (4/e), 2001.
- 3. D. A. Johns and K. Martin, Analog Integrated Circuit Design, Wiley, 1997.
- 4. R. Jacob Baker, CMOS Circuit Design, Layout, and Simulation, Wiley, (3/e), 2010.
- 5. P.E.Allen, D.R. Holberg, CMOS Analog Circuit Design, Oxford University Press, 2002.
- 6. Recent literature in Analog IC Design.

## **BASICS OF VLSI**

Weekly Teaching Hours	TH:03	Tut: 01	
Scheme of Marking	TH :60	Tests : 20 IA: 20	Total : 100

#### **Course Objective:**

А	To provide rigorous foundation in MOS and CMOS digital circuits.
В	To train the students in transistor budgets, clock speeds and the growing challenges of power consumption and productivity

#### **Course Outcomes:**

CO1	Learner will be able to implement the logic circuits using MOS and CMOS technology.
CO2	Learner will be able to analyze various circuit configurations and their applications.
CO3	Learner will be able to analyze the merits of circuits according to the technology and applications change.
CO4	Learner will be able to design low power CMOS VLSI circuits.
CO5	Learner will be able to understand the rapid advances in CMOS Technology.

## <u>UNIT I</u>

Introduction to CMOS circuits: MOS transistors, CMOS combinational logic gates, multiplexers, latches and flip-flops, CMOS fabrication and layout, VLSI design flow.

## <u>UNIT II</u>

MOS transistor theory: Ideal I-V and C-V characteristics, non-ideal I-V effects, DC transfer characteristics, Switch level RC delay models.

## <u>UNIT III</u>

CMOS technologies: Layout design rules, CMOS process enhancement, Technology related

CAD issues.

## <u>UNIT IV</u>

Circuit characterization and performance estimation: Delay estimation, Logical effort and

Transistor sizing, Power dissipation, Interconnect design margin, Reliability, Scaling.

## <u>UNIT V</u>

Circuit characterization and performance estimation: Power dissipation, Interconnect design margin, Reliability, Scaling.

## <u>UNIT VI</u>

Combinational circuit design: Static CMOS, Ratioed circuits, Cascode voltage switch logic, Dynamic circuits, Pass transistor circuits.

- 1. N.H.E.Weste, D. Harris, CMOS VLSI Design (3/e), Pearson, 2005.
- 2. J.Rabey, M. Pedram, Digital Integrated circuits (2/e), PHI, 2003.
- 3. Pucknell & Eshraghian, Basic VLSI Design, (3/e), PHI, 1996.
- 4. Recent literature in Basics of VLSI.

# ELECTIVE-I DIGITAL SYSTEM DESIGN

Weekly Teaching Hours	TH : 03	Tut:		
Scheme of Marking	TH :60	Tests : 20	IA: 20	Total : 100

#### **Course Objective:**

А	To get an idea about designing complex, high speed digital systems and how to
	implement such design

### **Course Outcomes:**

CO1	Learner will be able to identify mapping algorithms into architectures.
CO2	Learner will be able to understand various delays in combinational circuit and its optimization methods.
CO3	Learner will be able to understand circuit design of latches and flip-flops
CO4	Learner will be able to demonstrate combinational and sequential circuits of medium complexity that is based on VLSIs, and programmable logic devices.
CO5	Learner will be able to understand the advanced topics such as reconfigurable computing, partially reconfigurable, Pipeline reconfigurable architectures and block configurable.

## <u>UNIT I</u>

Mapping algorithms into Architectures: Data path synthesis, control structures, critical path and worst case timing analysis. FSM and Hazards.

## <u>UNIT II</u>

Combinational network delay. Power and energy optimization in combinational logic circuit. Sequential machine design styles. Rules for clocking. Performance analysis.

## <u>UNIT III</u>

Sequencing static circuits. Circuit design of latches and flip-flops. Static sequencing element methodology. Sequencing dynamic circuits. Synchronizers.

## <u>UNIT IV</u>

Data path and array subsystems: Addition / Subtraction, Comparators, counters, coding, multiplication and division.

## <u>UNIT V</u>

SRAM, DRAM, ROM, serial access memory, context addressable memory.

## <u>UNIT VI</u>

Reconfigurable Computing- Fine grain and Coarse grain architectures, Configuration architectures-Single context, Multi context, partially reconfigurable, Pipeline reconfigurable,

Block Configurable, Parallel processing.

- 1. N. H.E.Weste, D. Harris, CMOS VLSI Design (3/e), Pearson, 2005.
- 2. W.Wolf, FPGA- based System Design, Pearson, 2004.
- **3.** S.Hauck, A.DeHon, Reconfigurable computing: the theory and practice of FPGA-basedcomputation, Elsevier, 2008.
- 4. F.P. Prosser, D. E. Winkel, Art of Digital Design, 1987.
- 5. R.F.Tinde, Engineering Digital Design, (2/e), Academic Press, 2000.
- C. Bobda, Introduction to reconfigurable computing, Springer, 2007.
- **6.** M.Gokhale, P.S.Graham, Reconfigurable computing: accelerating computation with field-programmable gate arrays, Springer, 2005.
- 7. C.Roth, Fundamentals of Digital Logic Design, Jaico Publishers, V ed., 2009.
- 8. Recent literature in Digital System Design.

# ELECTIVE-I MODELING AND SYNTHESIS WITH VERILOG HDL

Weekly Teaching Hours

TH:03 Tut: --

Scheme of Marking TH :60 Tests : 20 IA: 20 Total : 100

### **Course Objective:**

А	To design combinational, sequential circuits using Verilog HDL.
В	To understand behavioral and RTL modeling of digital circuits.
С	To verify that a design meets its timing constraints, both manually and through the use of computer aided design tools.
D	To simulate, synthesize, and program their designs on a development board.
Е	To verify and design the digital circuit by means of Computer Aided Engineering tools which involves in programming with the help of Verilog HDL.

#### **Course Outcomes:**

CO1	Learner will be able to understand the basic concepts of verilog HDL
CO2	Learner will be able to demonstrate digital systems in verilog HDL at different levels of abstraction
CO3	Learner will be able to understand the simulation techniques and test bench creation.
CO4	Learner will be able to understand the design flow from simulation to synthesizable version
CO5	Learner will be able to understand the process of synthesis and post-synthesis

## <u>UNIT I</u>

Hardware modeling with the verilog HDL.Encapsulation, modeling primitives, different types of description.

## <u>UNIT II</u>

Logic system, data types and operators for modeling inverilog HDL.

## <u>UNIT III</u>

Verilog Models of propagation delay and net delay path delays and simulation, inertial delay effects and pulse rejection.

## <u>UNIT IV</u>

Behavioral descriptions in verilogHDL.Synthesis of combinational logic.

## <u>UNIT V</u>

HDL-based synthesis - technology-independent design, styles for synthesis of combinational and sequential logic, synthesis of finite state machines, synthesis of gated clocks, design partitions and hierarchical structures.

## <u>UNIT VI</u>

Synthesis of language constructs, nets, register variables, expressions and operators, assignments and compiler directives. Switch-level models in verilog. Design examples in verilog.

- 1. M.D.Ciletti, Modeling, Synthesis and Rapid Prototyping with the Verilog HDL, PHI, 1999.
- 2. S. Palnitkar, Verilog HDL A Guide to Digital Design and Synthesis, Pearson, 2003.
- 3. J Bhaskar, A Verilog HDL Primer (3/e), Kluwer, 2005.
- 4. M.G.Arnold, Verilog Digital Computer Design, Prentice Hall (PTR), 1999.
- 5. Recent literature in Modeling and Synthesis with Verilog HDL.

## ELECTIVE-I

## **OPTIMIZATIONS OF DIGITAL SIGNAL PROCESSING STRUCTURES FOR VLSI**

Weekly Teaching Hours	TH : 03	Tut:		
Scheme of Marking	TH :60	Tests: 20	IA: 20	Total : 100

#### **Course Objective:**

А	To understand the various VLSI architectures for digital signal processing.
В	To know the techniques of critical path and algorithmic strength reduction in the filter structures.
C	To enable students to design VLSI system with high speed and low power.
D	To encourage students to develop a working knowledge of the central ideas of implementation of DSP algorithm with optimized hardware.

### **Course Outcomes:**

CO1	Learner will be able to understand the overview of DSP concepts and design architectures for DSP algorithms.
CO2	Learner will be able to improve the overall performance of DSP system through various transformation and optimization techniques.
CO3	Learner will be able to perform pipelining and parallel processing on FIR and IIR systems to achieve highspeed and low power.
CO4	Learner will be able to optimize design in terms of computation complexity and speed.
CO5	Learner will be able to understand clock based issues and design asynchronous and wave pipelined systems.

## <u>UNIT I</u>

An overview of DSP concepts, Pipelining of FIR filters. Parallel processing of FIR filters.

Pipelining and parallel processing for low power, Combining Pipelining and Parallel Processing.

## <u>UNIT II</u>

Transformation Techniques: Iteration bound, Retiming, Folding and Unfolding

## <u>UNIT III</u>

Pipeline interleaving in digital filters. Pipelining and parallel processing for IIR filters. Low power IIR filter design using pipelining and parallel processing, Pipelined adaptive digital filters.

## <u>UNIT IV</u>

Algorithms for fast convolution: Cook-Toom Algorithm, Cyclic Convolution. Algorithmic strength reduction in filters and transforms: Parallel FIR Filters, DCT and inverse DCT,

Parallel Architectures for Rank-Order Filters.

## <u>UNIT V</u>

Synchronous pipelining and clocking styles, clock skew and clock distribution in bit level pipelined VLSI designs.

## <u>UNIT VI</u>

Wave pipelining, constraint space diagram and degree of wavepipelining, Implementation of wave-pipelined systems, Asynchronous pipelining.

## **TEXTBOOKS / REFERENCE:**

1. K.K.Parhi, VLSI Digital Signal Processing Systems, John-Wiley, 2007

2. U. Meyer -Baese, Digital Signal Processing with FPGAs, Springer, 2004

3. Wayne Burleson, KonstantinosKonstantinides, Teresa H. Meng, VLSI Signal Processing, 1996.

4. Richard J. Higgins, Digital signal processing in VLSI, 1990.

5. Sun Yuan Kung, Harper J. Whitehouse, VLSI and modern signal processing, 1985

6. Magdy A. Bayoumi, VLSI Design Methodologies for Digital Signal Processing, 2012

7. Earl E. Swartzlander, VLSI signal processing systems, 1986. Recent literature in

Optimizations of Digital Signal Processing Structures for VLSI.

# ELECTIVE-I COGNITIVE RADIO

Weekly Teaching Hours	TH : 03	Tut:		
Scheme of Marking	TH :60	Tests: 20	IA: 20	Total : 100

#### **Course Objectives:**

А	To understand the use of the SDR
В	To understand the stages of the evolution of SDR.
С	To study the applications of the Cognitive Radio.
D	To develop the system model for the spectrum sensing and spectrum access
	techniques in CR.

#### **Course Outcomes:**

CO1	Learner will be able to differentiate between SDR and CR
CO2	Learner will be able to evaluate the different spectrum sensing techniques for the
	cognitive radio.
CO3	Learner will be able to develop the system model for single carrier and multicarrier
	cognitive radio system.
CO4	Learner will be able to evaluate the different spectrum management techniques for
	cognitive radio system.
C05	Learner will be able to simulate and analyze the SDR and Cognitive radio systems

## <u>UNIT I</u>

Software Defined Radio Architecture - Digital Signal Processor and SDR Baseband Architecture, Reconfigurable Wireless Communication Systems, Unified Communication Algorithm, Reconfigurable OFDM Implementation, Reconfigurable OFDM and CDMA, Digital Radio Processing, Conventional RF, Digital Radio Processing (DRP) Based System Architecture

#### <u>UNIT II</u>

Cooperative Communications and Networks - Information Theory for Cooperative Communications, Fundamental Network Information, Multiple-access Channel with Cooperative Diversity, Cooperative Communications, Three-Node Cooperative Communications ,Multiple-Node Relay Network,Cooperative Wireless Networks, Benefits of Cooperation in Wireless Networks , Cooperation in Cluster-Based Ad-hoc Networks

#### UNIT III

Cognitive Radio Communications : Cognitive Radios and Dynamic Spectrum Access, The Capability of Cognitive Radios, Cognitive Radio cycle, Spectrum Sharing Models of DSA,

Opportunistic Spectrum Access: Basic Components, Networking The Cognitive Radios, Analytical Approach and Algorithms for Dynamic Spectrum Access, Dynamic Spectrum Access in Open Spectrum, Opportunistic Spectrum Access, Opportunistic Power Control, Fundamental Limits of Cognitive Radios, Mathematical Models Toward Networking Cognitive Radios, CR Link Model, Overlay CR Systems, Rate-Distance Nature.

## UNIT IV

Spectrum Sensing: Primary Signal Detection such as Energy Detector, Cyclo-stationary Feature Detector ,Matched Filter, Cooperative Sensing etc., Spectrum Sensing to Detect Specific Primary System , conventional Spectrum Sensing, Power Control , Power-Scaling Power Control ,Cooperative Spectrum Sensing , Spectrum Sensing for Cognitive OFDMA Systems , Discrimination of States of the Primary System, Spectrum Sensing Procedure, Spectrum Sensing for Cognitive Multi-Radio Networks , Multiple System Sensing , Radio Resource Sensing.

## <u>UNIT V</u>

Cognitive Radio Networks: Network Coding for Cognitive Radio Relay Networks, System Model, Network Capacity Analysis on Fundamental CRRN Topologies, Link Allocation, Numerical Results, Cognitive Radio Networks Architecture, Network Architecture, Links in CRN, IP Mobility Management in CRN, Terminal Architecture of CRN, Cognitive Radio Device Architecture, Re-configurable MAC, Radio Access Network Selection, QoS Provisional Diversity Radio Access Networks, Cooperative/Collaborative Diversity and Efficient Protocols, Statistical QoS Guarantees over Wireless Asymmetry Collaborative Relay Networks.

## <u>UNIT VI</u>

Spectrum access and sharing: Unlicensed Spectrum Sharing, Licensed Spectrum Sharing, Secondary(SSA) Spectrum Access, Non-Real-Time SSA, Real-Time SSA, Negotiated Access, Is Quality of Service Provisioning Possible in a Shared Band, Opportunistic Access ,Overlay Approach, Underlay Approach

#### **Text /Reference Books:**

- 1. Kwang-Cheng Chen, Ramjee Prasad, Cognitive Radio Networks, John Wiley & Sons Ltd.
- 2. Alexander M. Wyglinski, Maziar Nekovee, Y. Thomas Hou, Cognitive Radio Communications and Networks Principles and Practice, Elsevier publication.
- 3. Qusay H. Mahmoud, Cognitive Networks, John Wiley & Sons Ltd.

# <u>ELECTIVE-I</u> VLSI PROCESS TECHNOLOGY

Weekly Teaching Hours	TH : 03	Tut:	
Scheme of Marking	TH :60	Tests : 20 IA: 20	Total : 100

#### **Course Objective:**

A To provide rigorous foundation in MOS and CMOS fabrication pr	ocess.
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### **Course Outcomes:**

CO1	Learner will be able to understand various techniques involved in the VLSI fabrication process.
CO2	Learner will be able to understand the different lithography methods and etching process
CO3	Learner will be able to analyze the deposition and diffusion mechanisms.
CO4	Learner will be able to analyze the fabrication of NMOS, CMOS memory and bipolar devices
CO5	Learner will be able to understand the nuances of assembly and packaging of VLSI devices.

## <u>UNIT I</u>

Electron grade silicon. Crystal growth. Wafer preparation. Vapor phase and molecular beam epitaxy. SOI. Epitaxial evaluation. Oxidation techniques, systems and properties. Oxidation defects.

## <u>UNIT II</u>

Optical, electron, X-ray and ion lithography methods. Plasma properties, size, control, etch mechanism, etch techniques and equipments.

## <u>UNIT III</u>

Deposition process and methods. Diffusion in solids. Diffusion equation and diffusion mechanisms.

## <u>UNIT IV</u>

Ion implantation and metallization. Process simulation of ion implementation, diffusion, oxidation, epitaxy, lithography, etching and deposition.

## <u>UNIT V</u>

NMOS, CMOS, MOS memory and bipolar IC technologies. IC fabrication.

## <u>UNIT VI</u>

Analytical and assembly techniques. Packaging of VLSI devices.

- 1. S.M.Sze, "VLSI Technology (2/e)", McGraw Hill, 1988
- 2. W. Wolf, "Modern VLSI Design", (3/e), Pearson, 2002

# ELECTIVE-II ADVANCED COMPUTER ARCHITECTURE

Weekly Teaching Hours	TH : 03	Tut:		
Scheme of Marking	TH :60	Tests : 20	IA: 20	Total : 100

#### **Course Objective:**

А	То	give	an	exposure	on	look	ahead	pipelining-	parallelism,	multiprocessor
	sche	edulin	g, m	ultithreadii	ng ar	nd vari	ous mei	nory organiz	ations.	

#### **Course Outcomes:**

CO1	Learner will be able to apply the basic knowledge of partitioning and scheduling in Multiprocessors.
CO2	Learner will be able to analyze and design cache memory, virtual memory and shared memory organizations.
CO3	Learner will be able to distinguish and analyze the design properties of Linear and Non – Linear processors.
CO4	Learner will be able to analyze the principles of multithreading in hybrid Architectures.
CO5	Learner will be able to analyze any parallel programming models for various architectures and Applications.

## <u>UNIT I</u>

Multiprocessors and multi-computers. Multi-vector and SIMD computers. PRAM and VLSI

Models. Conditions of parallelism. Program partitioning and scheduling. Program flow mechanisms. Parallel processing applications. Speed up performance law.

## <u>UNIT II</u>

Advanced processor technology. Superscalar and vector processors. Memory hierarchy technology. Virtual memory technology. Cache memory organization. Shared memory organization.

## <u>UNIT III</u>

Linear pipeline processors. Non-linear pipeline processors. Instruction pipeline design. Arithmetic design. Superscalar and super pipeline design. Multiprocessor system interconnects. Message passing mechanisms.

#### UNIT IV

Vector Processing principle. Multivector multiprocessors, Compound Vector processing. Principles of multithreading, Fine grain multicomputer. Scalable and multithread architectures. Dataflow and hybrid architectures.

## <u>UNIT V</u>

Parallel programming models. Parallel languages and compilers. Parallel programming environments. Synchronization and multiprocessing modes.

## <u>UNIT VI</u>

Message passing program development. Mapping programs onto multicomputer. Multiprocessor UNIX design goals. MACH/OS kernel architecture. OSF/1 architecture and applications.

- 1 M.J. Quinn, "Designing Efficient Algorithms for Parallel Computer', McGraw Hill,
- 2 K. Hwang, "Advanced Computer Architecture ", Tata McGraw Hill, 2001.
- 3 W. Stallings," Computer Organization and Architecture", McMillan, 1990
- 4 Recent literature in Advanced Computer Architecture.

# ELECTIVE-II LOW POWER VLSI CIRCUITS

Weekly Teaching Hours	TH : 03	Tut:		
Scheme of Marking	TH :60	Tests: 20	IA: 20	Total : 100

#### **Course Objective:**

А	To expose the students to the low voltage device modeling, low voltage, low power
	VLSI CMOS circuit design.

#### **Course Outcomes:**

CO1	Learner will be able to acquire the knowledge about various CMOS fabrication process and its modeling.
CO2	Learner will be able to infer about the second order effects of MOS transistor characteristics.
CO3	Learner will be able to analyze and implement various CMOS static logic circuits.
CO4	Learner will be able to understand the design of various CMOS dynamic logic circuits.
CO5	Learner will be able to understand the design techniques low voltage and low power CMOS circuits for various applications.
CO6	Learner will be able to understand the different types of memory circuits and their design.
CO7	Learner will be able to design and implement various structures for low power applications.

## <u>UNIT I</u>

Evolution of CMOS technology.0.25  $\mu$ m and 0.1  $\mu$ m technologies. Shallow trench isolation.

Lightly-doped drain. Buried channel. BiCMOS and SOI CMOS technologies. Second order effects and capacitance of MOS devices.

## <u>UNIT II</u>

CMOS inverters, static logic circuits of CMOS, pass transistor, BiCMOS, SOI CMOS and low power CMOS techniques

## <u>UNIT III</u>

Basic concepts of dynamic logic circuits. Various problems associated with dynamic logic circuits.

## <u>UNIT IV</u>

Differential, BiCMOS and low voltage dynamic logic circuits.

## <u>UNIT V</u>

Different types of memory circuits

## <u>UNIT VI</u>

Adder circuits, Multipliers and advanced structures – PLA, PLL, DLL and processing unit.

## **TEXTBOOKS / REFERENCE:**

1 J.Rabaey, "Low Power Design Essentials (Integrated Circuits and Systems)",

Springer, 2009

2 J.B.Kuo&J.H.Lou, "Low-voltage CMOS VLSI Circuits", Wiley, 1999.

3 A.Bellaowar& M.I.Elmasry,"Low power Digital VLSI Design, Circuits and Systems", Kluwer, 1996.

4 Recent literature in Low Power VLSI Circuits.

# ELECTIVE-II VLSI DIGITAL SIGNAL PROCESSING SYSTEMS

Weekly Teaching Hours	TH : 03	Tut:		
Scheme of Marking	TH :60	Tests : 20	IA: 20	Total : 100

**Course Objective::** 

А	To enable students to design VLSI systems with high speed and low power.
В	To encourage students to develop a working knowledge of the central ideas of implementation of DSP algorithm with optimized hardware.

## **Course Outcomes:**

CO1	Learner will be able to acquire the knowledge of round off noise computation and numerical strength reduction.
CO2	Learner will be able to design Bit level and redundant arithmetic Architectures.

## <u>UNIT I</u>

An overview of DSP concepts, Representations of DSP algorithms. Systolic Architecture Design: FIR Systolic Array, Matrix-Matrix Multiplication, 2D Systolic Array Design. Digital

Lattice Filter Structures: Schur Algorithm, Derivation of One-Multiplier Lattice Filter, Normalized Lattice Filter, Pipelining of Lattice Filter.

## <u>UNIT II</u>

Scaling and Round off Noise - State variable description of digital filters, Scaling and Round off Noise computation, Round off Noise in Pipelined IIR Filters, Round off Noise Computation using state variable description, Slow-down, Retiming and Pipelining.

## <u>UNIT III</u>

Bit level arithmetic Architectures- parallel multipliers, interleaved floor-plan and bit-plane based digital filters, Bit serial multipliers, Bit serial filter design and implementation, Canonic signed digit arithmetic, Distributed arithmetic.

## <u>UNIT IV</u>

Redundant arithmetic -Redundant number representations, carry free radix-2 addition and subtraction, Hybrid radix-4 addition, Radix-2 hybrid redundant multiplication architectures, data format conversion, Redundant to Non-redundant converter.

## <u>UNIT V</u>

Numerical Strength Reduction - Sub expression Elimination, Multiple Constant Multiplication,

## <u>UNIT VI</u>

Sub expression sharing in Digital Filters, Additive and Multiplicative Number Splitting.

- 1 K.K.Parhi, "VLSI Digital Signal Processing Systems", John-Wiley, 2007.
- 2 JU. Meyer -Baese, Digital Signal Processing with FPGAs, Springer, 2004.
- 3 Recent literature in VLSI Digital Signal Processing Systems.

# ELECTIVE-II ADVANCED DIGITAL DESIGN

Weekly Teaching Hours	TH : 03	Tut:		
Scheme of Marking	TH :60	Tests: 20	IA: 20	Total : 100

#### **Course Objective:**

Α	To make the students learn about graphical models and state diagram in designing optimized digital circuits.
В	To provide the students a detailed knowledge of scheduling algorithm, synthesis of pipelined circuits and scheduling pipelined circuits
С	To enable the students to design digital design with advanced technique like Sequential logic optimization and test the designed circuit Testability considerations.

#### **Course Outcomes:**

CO1	Learner will be able to understand advanced state of art techniques of digital design.
CO2	Learner will be able to synthesize the circuits and evaluate its performance in terms of area, power and speed.
CO3	Learner will be able to understand use of scheduling algorithm.
CO4	Learner will be able to gain in-depth knowledge of sequential digital circuits designed using resource sharing.
CO5	Learner will be able to understand synchronization across clock domains, timing analysis, and Testability considerations

## <u>UNIT I</u>

Different types of graphs. Combinational optimization- Graph optimization problems and algorithms. Boolean functions, statisfiability and cover. Abstract models, state diagrams. Data flow and sequencing graphs, compilation and behavioral optimization.

## <u>UNIT II</u>

Architectural synthesis - Circuit specifications for architectural synthesis. Temporal domain, spatial domain, hierarchical models. Synchronization problems. Area and performance estimation. Strategies for architectural optimization, Data path synthesis of pipelined circuits.

## <u>UNIT III</u>

Scheduling algorithms-Scheduling with and without constraints. Scheduling algorithms for extended sequencing models. Scheduling pipelined circuits.

## <u>UNIT IV</u>

Resource sharing and binding. Sharing and binding for resource dominated circuits and general circuits. Concurrent binding and scheduling. Resource sharing and binding for nonscheduled sequencing graphs.

## <u>UNIT V</u>

Sequential logic optimization-sequential circuit optimization using state based models and network models

## <u>UNIT VI</u>

Implicit finite state machine. Traversal methods. Testability considerations for synchronous circuits.

## **TEXTBOOKS / REFERENCE:**

- 1 G.DeMicheli, "Synthesis and optimization of Digital circuits", McGraw Hill, 1994.
- 2 C. Roth, "Fundamentals of Digital Logic Design", Jaico Publishers, V ed., 2009.
- 3 Balabanian, "Digital Logic Design Principles", Wiley publication, 2000.
- 4 J. F. Wakerly,"Digital Design principles and practices", 3rd edition, PHI publication, .

5. S.Brown, "Fundamentals of digital logic", Tata McGraw Hill publication, 2007.

- 6. N. N. Biswas, "Logic Design Theory", Prentice Hall of India, 2001
- 7 . John M Yarbrough, "Digital Logic applications and Design", Thomson Learning.
- 8. Recent literature in Advanced Digital Design.

## ELECTIVE-II RF CIRCUITS

Weekly Teaching Hours	TH : 03	Tut:		
Scheme of Marking	TH :60	Tests: 20 IA	: 20	Total : 100

#### **Course Objective:**

А

To impart knowledge on basics of IC design at RF frequencies.

### **Course Outcomes:**

CO1	Learner will be able to understand the Noise models for passive components and noise theory
CO2	Learner will be able to analyze the design of a high frequency amplifier
CO3	Learner will be able to understand the different LNA topologies & design techniques
CO4	Learner will be able to distinguish between different types of mixers
CO5	Learner will be able to analyze the various types of synthesizers, oscillators and their characteristics.

## <u>UNIT I</u>

Characteristics of passive IC components at RF frequencies – interconnects, resistors, capacitors, inductors and transformers – Transmission lines. Noise – classical two-port noise theory, noise models for active and passive components

## <u>UNIT II</u>

High frequency amplifier design – zeros as bandwidth enhancers, shunt-series amplifier, fT doublers, neutralization and unilateralization

## <u>UNIT III</u>

Low noise amplifier design – LNA topologies, power constrained noise optimization, linearity and large signal performance

## <u>UNIT IV</u>

Mixers – multiplier-based mixers, subsampling mixers, diode-ring mixers RF power amplifiers – Class A, AB, B, C, D, E and F amplifiers, modulation of power amplifiers, linearity considerations.

## <u>UNIT V</u>

Oscillators: describing functions, resonators, negative resistance oscillators,

## <u>UNIT VI</u>

Synthesizers: synthesis with static moduli, synthesis with dithering moduli, combination synthesizers - phase noise considerations.

### **TEXTBOOKS / REFERENCE:**

1. T.homas H. Lee, "The Design of CMOS Radio-Frequency Integrated Circuits", 2<sup>nd</sup> ed., Cambridge, UK: Cambridge University Press, 2004.

2. B.Razavi, "RF Microelectronics", 2nd Ed., Prentice Hall, 1998.

3. Abidi, P.R. Gray, and R.G. Meyer, eds., "Integrated Circuits for Wireless

Communications", New York: IEEE Press, 1999.

4. R. Ludwig and P. Bretchko, "RF Circuit Design, Theory and Applications", Pearson, 2000.

5. Mattuck, A., "Introduction to Analysis", Prentice-Hall, 1998.

6. Recent literature in RF Circuits.

# ELECTIVE-II MIXED - SIGNAL CIRCUIT DESIGN

Weekly Teaching Hours	TH : 03	Tut:		
Scheme of Marking	TH :60	Tests : 20	IA: 20	Total : 100

#### **Course Objective:**

А	To make the students to understand the design and performance measures concept of
	mixed signal circuit.

### **Course Outcomes:**

CO1	Learner will be able to understand the fundamentals of data converters and also optimized their performances.
CO2	Learner will be able to understand the design methodology for mixed signal IC design using gm/Id concept.
CO3	Learner will be able to analyze the design of current mirrors and operational amplifiers
CO4	Learner will be able to design the CMOS digital circuits and implement its layout.
CO5	Learner will be able to design the frequency and Q tunable time domain filters.

## <u>UNIT I</u>

Concepts of Mixed-Signal Design and Performance Measures.

## <u>UNIT II</u>

Fundamentals of DataConverters.Nyquist Rate Converters and Over sampling Converters.

## <u>UNIT III</u>

Design methodology for mixed signal IC design using gm/Id concept.

## <u>UNIT IV</u>

Design of Current mirrors.References.Comparators and Operational Amplifiers.

## <u>UNIT V</u>

CMOS Digital Circuits Design: Design of MOSFET Switches and Switched-Capacitor

Circuits, Layout Considerations.

## <u>UNIT VI</u>

Design of frequency and Q tunable continuous time filters.

## **TEXTBOOKS / REFERENCE:**

1. R. Jacob Baker, Harry W. Li, David E. Boyce, CMOS, Circuit Design, Layout, and Simulation, Wiley-IEEE Press, 1998

2. David A. Johns and Ken Martin, Analog Integrated Circuit Design, John Wiley and Sons, 1997.

#### **COMMUNICATION SKILLS**

Weekly Teaching Hours	TH: 02	Practical: -	
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Scheme of MarkingTH: --IA: 25PR/OR: 25Total: 50

#### **Course Objectives:**

А	To become more effective confident speakers and deliver persuasive presentations
В	To develop greater awareness and sensitivity to some important considerations in interpersonal communication and learn techniques to ensure smoother interpersonal relations

#### **Course Outcomes:**

CO1	Learner will be able to understand the fundamental principles of effective business communication
CO2	Learner will be able to apply the critical and creative thinking abilities necessary for effective communication in today's business world
CO3	Learner will be able to organize and express ideas in writing and speaking to produce messages suitably tailored for the topic, objective, audience, communication medium and context
CO4	Learner will be able to demonstrate clarity, precision, conciseness and coherence in your use of language
CO5	Learner will be able to become more effective confident speakers and deliver persuasive presentations

## <u>UNIT I</u>

Introduction to communication, Necessity of communication skills, Features of good communication, Speaking skills, Feedback & questioning technique, Objectivity in argument

## <u>UNIT II</u>

Verbal and Non-verbal Communication, Use and importance of non-verbal communication while using a language, Study of different pictorial expressions of non-verbal communication and their analysis

## <u>UNIT III</u>

Academic writing, Different types of academic writing, Writing Assignments and Research Papers, Writing dissertations and project reports

## <u>UNIT IV</u>

Presentation Skills: Designing an effective Presentation, Contents, appearance, themes in a presentation; Tone and Language in a presentation, Role and Importance of different tools for effective presentation

## <u>UNIT V</u>

Motivation/ Inspiration: Ability to shape and direct working methods according to selfdefined criteria; Ability to think for oneself, Apply oneself to a task independently with selfmotivation, Motivation techniques: Motivation techniques based on needs and field situations

## <u>UNIT VI</u>

Self-management, Self-evaluation, Self-discipline, Self-criticism, Recognition of one's own limits and deficiencies, dependency etc. Self-awareness, Identifying one's strengths and weaknesses, Planning & Goal setting, Managing self-emotions, ego, pride leadership & Team dynamics

- 1. Mitra, Barun, Personality Development and Soft Skills, Oxford University Press, 2016.
- **2.** Ramesh, Gopalswamy, The Ace of Soft Skills: Attitude, Communication and Etiquette for Success, Pearson Education, 2013.
- **3.** Covey, Stephen R., Seven Habits of Highly Effective People: Powerful Lessons in Personal Change, Simon and Schuster, 09-Nov-2004
- 4. Rosenberg Marshall B., Nonviolent Communication: A Language of Life, PuddleDancer Press, 01-Sep-2003

	PG	LAB-I		
Weekly Teaching Hours	TH:		Practical: 03	
Scheme of Marking	TH:	IA: 25	PR/OR: 25	Total: 50

Practical's of the Lab - I shall be based on the courses of first semester. The lab work shall consist of hands on experiments on the different software and hardware platforms related to the syllabus.

### VLSI SYSTEM TESTING

Weekly Teaching Hours	TH : 03	Tut: 01		
Scheme of Marking	TH :60	Tests : 20	IA: 20	Total : 100

#### **Course Objective:**

А	To expose the students, the basics of testing techniques for VLSI circuits and Test
	Economics.

#### **Course Outcomes:**

CO1	Learner will be able to apply the concepts in testing which can help them design a better yield in IC design.
CO2	Learner will be able to tackle the problems associated with testing of semiconductor circuits at earlier design levels so as to significantly reduce the testing costs.
CO3	Learner will be able to analyze the various test generation methods for static & dynamic CMOS circuits.
CO4	Learner will be able to identify the design for testability methods for combinational & sequential CMOS circuits.
CO5	Learner will be able to recognize the BIST techniques for improving testability.

## <u>UNIT I</u>

Basics of Testing: Fault models, Combinational logic and fault simulation, Test generation for Combinational Circuits. Current sensing based testing. Classification of sequential ATPG methods. Fault collapsing and simulation

## UNIT II

Universal test sets: Pseudo-exhaustive and iterative logic array testing. Clocking schemes for delay fault testing. Testability classifications for path delay faults. Test generation and fault simulation for path and gate delay faults.

## <u>UNIT III</u>

CMOS testing: Testing of static and dynamic circuits. Fault diagnosis: Fault models for diagnosis, Cause-effect diagnosis, Effect-cause diagnosis.

#### <u>UNIT IV</u>

Design for testability: Scan design, Partial scan, use of scan chains, boundary scan, DFT for other test objectives, Memory Testing.

#### <u>UNIT V</u>

Built-in self-test: Pattern Generators, Estimation of test length, Test points to improve Testability.

## <u>UNIT VI</u>

Analysis of aliasing in linear compression, BIST methodologies, BIST for delay fault testing.

- 1. N. Jha& S.D. Gupta, "Testing of Digital Systems", Cambridge, 2003.
- **2.** W. W. Wen, "VLSI Test Principles and Architectures Design for Testability", Morgan Kaufmann Publishers. 2006
- **3.** Michael L. Bushnell &Vishwani D. Agrawal," Essentials of Electronic Testing for Digital, memory & Mixed signal VLSI Circuits", Kluwar Academic Publishers. 2000.
- 4. P. K. Lala," Digital circuit Testing and Testability", Academic Press. 1997.
- **5.** M. Abramovici, M. A. Breuer, and A.D. Friedman, "Digital System Testing and Testable Design", Computer Science Press, 1990.
- 6. Recent literature in VLSI System Testing.
# **DESIGN OF ASICS**

Weekly Teaching Hours	TH : 03	Tut: 01	
Scheme of Marking	TH :60	Tests : 20 IA: 20	Total : 100

# **Course Objective:**

А	To prepare the student to be an entry-level industrial standard ASIC or FPGA designer.
В	To give the student an understanding of issues and tools related to ASIC/FPGA design and implementation.
С	To give the student an understanding of basics of System on Chip and Platform based design.
D	To give the student an understanding of High performance algorithms

# **Course Outcomes:**

CO1	Learner will be able to demonstrate VLSI tool-flow and appreciate FPGA and CPLD architectures
CO2	Learner will be able to understand the issues involved in ASIC design, including technology choice, design management and tool-flow.
CO3	Learner will be able to understand the algorithms used for ASIC construction
CO4	Learner will be able to understand Full Custom Design Flow and Tool used
CO5	Learner will be able to understand Semicustom Design Flow and Tool used - from RTL to GDS and Logical to Physical Implementation
CO6	Learner will be able to understand about STA, LEC, DRC, LVS, DFM
CO7	Learner will be able to understand the basics of System on Chip and on chip communication architectures appreciate high performance algorithms for ASICs

# <u>UNIT I</u>

Introduction to Technology, Types of ASICs, VLSI Design flow, Design and Layout Rules, Programmable ASICs - Antifuse, SRAM, EPROM, EEPROM based ASICs. Programmable ASIC logic cells and I/O cells. Programmable interconnects. Advanced FPGAs and CPLDs and Soft-core processors.

# <u>UNIT II</u>

ASIC physical design issues, System Partitioning, Floorplanning and Placement. Algorithms: K-L, FM, Simulated annealing algorithms. Full Custom Design: Basics, Needs & Applications. Schematic and layout basics, Full Custom Design Flow.

# <u>UNIT III</u>

Semicustom Approach: Synthesis (RTL to GATE netlist) - Introduction to Constraints (SDC), Introduction to Static Timing Analysis (STA). Place and Route (Logical to Physical Implementation): Floorplan and Power-Plan, Placement, Clock Tree Synthesis (clock planning), Routing, Timing Optimization, GDS generation.

# <u>UNIT IV</u>

Extraction, Logical equivalence and STA: Parasitic Extraction Flow, STA: Timing Flow, LEC: Introduction, flow and Tools used. Physical Verification: Introduction, DRC, LVS and basics of DFM.

# <u>UNIT V</u>

System-On-Chip Design - SoC Design Flow, Platform-based and IP based SoC Designs, Basic Concepts of Bus-Based Communication Architectures.

# <u>UNIT VI</u>

High performance algorithms for ASICs/ SoCs as case studies – Canonic Signed Digit Arithmetic, KCM, Distributed Arithmetic, High performance digital filters for sigma-delta ADC.

# **TEXTBOOKS / REFERENCE:**

- 1. N. Jha & S.D. Gupta, "Testing of Digital Systems", Cambridge, 2003.
- 2. M.J.S. Smith : Application Specific Integrated Circuits, Pearson, 2003
- 3. Sudeep Pasricha and Nikil Dutt, On-Chip Communication Architectures System on Chip Interconnect, Elsevier, 2008
- 4. H. Gerez, Algorithms for VLSI Design Automation, John Wiley, 1999
- 5. Jan. M.Rabaey et al, Digital Integrated Circuit Design Perspective (2/e), PHI 2003
- 7. David A.Hodges, Analysis and Design of Digital Integrated Circuits (3/e), MGH 2004
- 8. Hoi-Jun Yoo, KangminLeeand Jun Kyong Kim, Low-Power NoC for HighPerformanceSoC Design, CRC Press, 2008
- 9. An Integrated Formal Verification solution DSM sign-off market trends,<u>www.cadence.com</u>.

# **ELECTIVE-III**

# FUNCTIONAL VERIFICATION USING HARDWARE VERIFICATION LANGUAGES

Weekly Teaching Hours	TH : 03	Tut:		
Scheme of Marking	TH :60	Tests : 20	IA: 20	Total : 100

### **Course Objective:**

A Learn to use verification tools and experiment on actual circuits designed in industry

### **Course Outcomes:**

CO1	Learner will be able to understand fundamentals of data converters and also optimized their performances.
CO2	Learner will be able to understand the design methodology for mixed signal IC design using gm/Id concept
CO3	Learner will be able to analyze the design of current mirrors and operational amplifiers
CO4	Learner will be able to design the CMOS digital circuits and implement its layout.
CO5	Learner will be able to design the frequency and Q tunable time domain filters.

# <u>UNIT I</u>

System Verilog (SV) - Data Types, Arrays, Structures, Unions, Procedural Blocks, Tasks & Functions, Procedural Statements, Interfaces, Basic OOPs, Randomization, Threads & Inter Process Communication, Advanced OOPs & Test bench guidelines, Advanced Interfaces

# <u>UNIT II</u>

A Complete System Verilog Test Bench (SVTB), Functional Coverage in System Verilog, Interfacing with C, FSM Modeling with SV, Connecting Test bench & Design, Behavioral & Transaction Level Modeling with SV.

# UNIT III

System Verilog Assertions (SVA) – Introduction to SVA, Building blocks, Properties, Boolean expressions, Sequence, Single & Multiple Clock definitions, Implication operators (Overlapping & Non-overlapping), Repeatition operators, Built-in System functions (\$past, \$stable, \$onehot, \$onehot0, \$isunknown), Constructs (ended, and, intersect, or, first\_match,t throughout, within, disableiff, expect, matched, if –else), assertion directives, nested implication, formal arguments in property

# <u>UNIT IV</u>

SVA using local variables, calling subroutines, SVA for functional coverage, Connecting SVA to the Design or Test bench, SVA for FSMs, Memories, Protocol checkers, SVA Simulation Methodology

# <u>UNIT V</u>

Assertions: Practice & Methodology, Re-use of Assertions, Tracking coverage with Assertions, Using SVA with other languages.

# <u>UNIT VI</u>

Functional Verification coverage using design, verification languages and implementation standards: Verilog IEEE 1364, VHDL IEEE 1076, System Verilog IEEE 1800, Property Specific Language (PSL) IEEE 1850, System C<sup>™</sup> IEEE 1666, Encryption IEEE 1735, e Verification Language IEEE 1647, Open Verification Methodology (OVM) and Universal Verification Methodology (UVM).

# **TEXTBOOKS / REFERENCE:**

1. Stuart Sutherland, Simon Davidmann, System Verilog for design: a guide to using System Verilog for hardware design and modeling published by Springer, 2004 ISBN 1402075308, 9781402075308

2. System Verilog for Verification: A Guide to Learning the Test bench Language Features by Chris Spear Edition: 2, Published by Springer, 2008 ISBN 0387765298, 9780387765297

3. Srikanth Vijayaraghavan& MeyyappanRamanathan , A Practical guide for System Verilog Assertions Published by Springer, 2005 ISBN 0387260498, 9780387260495

4. Faisal I.Haque, Jonathan Michelson, KhizarA.Khan , The Art of Verification with System Verilog Assertions Published by Verification Central 2006 ISBN-13:978-0-9711994--5

5. Prakash Rashinkar, Peter Paterson, Leena Singh, System-on-a-Chip Verification: Methodology and Techniques, Published by Kluwer Academic Publishers 2004, New York, ISBN-0-306-46995-2.

6. Janick Bergeron, Writing test benches using System Verilog, Published by Birkhäuser, 2006 ISBN 0387292217, 9780387292212

7.. Ben Cohen, cohen, Venkataramanan, Kumari, SrinivasanVenkataramanan, Ajeetha Kumari SystemVerilog Assertions Handbook: --for Formal and Dynamic Verification - Published by vhdlcohen publishing, 2005 (ISBN 0970539479, 9780970539472).

8. An Integrated Formal Verification solution DSM sign-off market trends, www.cadence.com.

9. Recent literature in Functional Verification using Hardware Verification Languages.

# ELECTIVE-III HIGH SPEED SYSTEM DESIGN

Weekly Teaching Hours	TH : 03	Tut: -		
Scheme of Marking	TH :60	Tests : 20	IA: 20	Total : 100

### **Course Objective:**

А	The requirement that systems perform complex tasks in a time frame considered comfortable by humans
В	The ability of component manufacturers to produce high-speed devices.

# **Course Outcomes:**

CO1	Learner will be able to understand Integrity and stability of ground and power
CO2	Learner will be able to understand Termination and careful layout
CO3	Learner will be able to understand Noise suppression

# <u>UNIT I</u>

Functions of an Electronic Package, Packaging Hierarchy, IC packaging requirements and properties; materials and substrates; Interconnect Capacitance, Resistance and Inductance fundamentals;; IC assembly: , Wire bonding, Tape Automated Bonding, Flip Chip, waferlevel packaging; impact on reliability and testability

# <u>UNIT II</u>

Overview of Transmission line theory, Clock Distribution, Noise Sources, power Distribution, signal distribution, EMI; crosstalk and nonideal effects; signal integrity: impact of packages, vias, traces, connectors; non-ideal return current paths, high frequency power delivery, simultaneous switching noise; system-level timing analysis and budgeting; methodologies for design of high speed buses; radiated emissions and minimizing system noise.

# <u>UNIT III</u>

Practical aspects of measurement at high frequencies; high speed oscilloscopes and logic analyzers.

# <u>UNIT IV</u>

Printed Circuit Board: Anatomy, CAD tools for PCB design, Standard fabrication, Microvia Boards. Board Assembly: Surface Mount Technology, Through Hole Technology, Process Control and Design challenges. Thermal Management, Heat transfer fundamentals, Thermal conductivity and resistance, Conduction, convection and radiation cooling requirements

# <u>UNIT V</u>

Reliability, Basic concepts, Environmental interactions. Thermal mismatch and fatigue failures thermo mechanically induced electrically induced chemically induced.

# <u>UNIT VI</u>

Electrical Testing: System level electrical testing, Interconnection tests, Active Circuit Testing, Design for Testability.

# **TEXTBOOKS / REFERENCE:**

- 1. Howard Johnson , Martin Graham, High Speed Digital Design: A Handbook of Black Magic, Prentice Hall, 1993
- High-Speed Digital System Design: A Handbook of Interconnect Theory and Design Practices", Stephen H. Hall, Garrett W. Hall, James A. McCall, August 2000, Wiley IEEE Press
- 3. Tummala, Rao R., Fundamentals of Microsystems Packaging, McGraw Hill, 2001
- 4 William J. Dally, John W. Poulton, Digital Systems Engineering, Cambridge University Press, 2008)
- 5 R.G. Kaduskar and V.B.Baru, Electronic Product design, Wiley India, 2011. 5. Recent literature in High Speed System Design.

# ELECTIVE-III HIGH SPEED COMMUNICATION NETWORKS

Course Objective:				
Scheme of Marking	TH :60	Tests : 20	IA: 20	Total : 100
Weekly Teaching Hours	TH : 03	Tut: -		

# A To impart the students a thorough exposure to the various high speed networking technologies and to analyse the methods adopted for performance modeling, traffic management and routing

# **Course Outcomes:**

CO1	Learner will be able to compare and analyze the fundamental principles of various high speed communication networks and their protocol architectures
CO2	Learner will be able to analyze the methods adopted for performance modeling of traffic flow and estimation
CO3	Learner will be able to understand the congestion control issues and traffic management in TCP/IP and ATM networks
CO4	Learner will be able to compare, analyse and implement the various routing protocols in simulation software tools
CO5	Learner will be able to examine the various services

# <u>UNIT I</u>

The need for a protocol architecture, The TCP/IP protocol architecture, Internetworking, Packet switching networks, Frame relay networks, Asynchronous Transfer mode (ATM) protocol architecture, High speed LANs. Multistage networks

# <u>UNIT II</u>

Overview of probability and stochastic process, Queuing analysis, single server and multiserver queues, queues with priorities, networks of queues, Self similar Data traffic.

# <u>UNIT III</u>

Congestion control in data networks and internets, Link level flow and error control, TCP traffic control, Traffic and congestion control in ATM networks.

# <u>UNIT IV</u>

Overview of Graph theory and least cost paths, Interior routing protocols, Exterior routing protocols and multicast.

# <u>UNIT V</u>

Quality of service in IP networks, Integrated and differentiated services, Protocols for QOS support-Resource reservation protocol,

# <u>UNIT VI</u>

Multiprotocol label switching, Real time transport protocol

# **TEXTBOOKS / REFERENCE:**

1. W. Stallings," High Speed networks and Internets", second edition, Pearson Education, 2002

- 2. A Pattavina,"Switching Theory", Wiley, 1998.
- 3. J. F. Kurose and K. W. Ross", Computer networking" 3rd edition, Pearson education, 2005

4. Mischa Schwartz," Telecommunication networks, protocols, modeling and analysis", Pearson education,2004

5. Giroux, N. and Ganti, S." Quality of service in ATM networks", Prentice Hall ,1999

6. Recent literature in High Speed Communication Networks.

# ELECTIVE-III DSP ARCHITECTURE

Weekly Teaching Hours	TH : 03	Tut: -		
Scheme of Marking	TH :60	Tests : 20	IA: 20	Total : 100

### **Course Objective:**

А	To give an exposure to the various fixed point and floating point DSP architectures
	and to implement real time applications using these processors

# **Course Outcomes:**

CO1	Learner will be able to understand the architecture details fixed and floating point DSPs
CO2	Learner will be able to infer about the control instructions, interrupts, and pipeline operations, memory and buses.
CO3	Learner will be able to understand the features of on-chip peripheral devices and its interfacing with real time application devices
CO4	Learner will be able to implement the signal processing algorithms and applications in DSPs
CO5	Learner will be able to understand the architecture of advanced DSPs

# <u>UNIT I</u>

Fixed-point DSP architectures. TMS320C54X, ADSP21XX, DSP56XX architecture details. Addressing modes. Control and repeat operations. Interrupts. Pipeline operation. Memory Map and Buses. TMS320C55X architecture and its comparison

# <u>UNIT II</u>

Floating-point DSP architectures. TMS320C67X, DSP96XX architectures. Cache architecture. Floating-point Data formats. On-chip peripherals. Memory Map and Buses.

# UNIT III

On-chip peripherals and interfacing. Clock generator with PLL. Serial port. McBSP. Parallel port. DMA. EMIF.

# <u>UNIT IV</u>

Serial interface- Audio codec.Sensors. A/D and D/A interfaces. Parallel interface- RAM and FPGA. RF transceiver interface.

# <u>UNIT V</u>

DSP tools and applications. Implementation of Filters, DFT, QPSK Modem, Speech processing. Video processing, Video Encoding / Decoding. Biometrics.Machine Vision. High performance computing (HPC)

# <u>UNIT VI</u>

Digital Media Processors.Video processing sub systems.Multi-core DSPs. OMAP.CORTEX, SHARC, SIMD, MIMD Architectures.

# **TEXTBOOKS / REFERENCE:**

1. B.Venkataramani&M.Bhaskar, Digital Signal Processor, Architecture, Programming and Applications",(2/e), McGraw- Hill,2010

2. S.Srinivasan&Avtar Singh, Digital Signal Processing, Implementations using DSP Microprocessors with Examples from TMS320C54X, Brooks/Cole, 2004

3. S.M.Kuo&Woon-SengS.Gan, Digital Signal Processors: Architectures, Implementations, and Applications, Printice Hall, 2004.

4. N. Kehtarnavaz& M. Kerama, DSP System Design using the TMS320C6000, Printice Hall, 2001.

5. S.M. Kuo&B.H.Lee, Real-Time Digital Signal Processing, Implementations, Applications and Experiments with the TMS320C55X, John Wiley, 2001.

6. Recent literature in DSP Architecture

# **ELECTIVE-III**

### **RF MEMS**

Weekly Teaching Hours	TH : 03	Tut: -		
Scheme of Marking	TH :60	Tests : 20	IA: 20	Total : 100

### **Course Objective:**

A To impart knowledge on basics of MEMS and their applications in RF circuit design

# **Course Outcomes:**

CO1	Learner will be able to understand the Micromachining Processes
CO2	Learner will be able to understand the design and applications of RF MEMS inductors and capacitors
CO3	Learner will be able to analyze RF MEMS Filters and RF MEMS Phase Shifters
CO4	Learner will be able to understand suitability of micro-machined transmission lines for RF MEMS
CO5	Learner will be able to understand the Micro-machined Antennas and Reconfigurable Antennas

# <u>UNIT I</u>

Micromachining Processes - methods, RF MEMS relays and switches. Switch parameters. Actuation mechanisms. Bistable relays and micro actuators. Dynamics of switching operation

# <u>UNIT II</u>

MEMS inductors and capacitors. Micro-machined inductor. Effect of inductor layout. Modeling and design issues of planar inductor. Gap-tuning and area-tuning capacitors. Dielectric tunable capacitors

# <u>UNIT III</u>

MEMS phase shifters. Types. Limitations. Switched delay lines. Fundamentals of RF MEMS Filters

# <u>UNIT IV</u>

Micro-machined transmission lines. Coplanar lines. Micro-machined directional coupler and mixer.

# <u>UNIT V</u>

Micro-machined antennas. Microstrip antennas – design parameters.

# <u>UNIT VI</u>

Micromachining to improve performance. Reconfigurable antennas.

# **TEXTBOOKS / REFERENCE:**

1. Vijay. K. Varadan, K.J. Vinoy, and K.A. Jose, RF MEMS and their Applications, Wiley-India, 2011.

2. H. J. D. Santos, RF MEMS Circuit Design for Wireless Communications, Artech House, 2002.

- 3. G. M. Rebeiz, RF MEMS Theory, Design, and Technology, Wiley, 2003.
- 4. Recent literature in RF MEMS.

<b>Elective IV</b>				
	Computer Aide	d Design for	VLSI	
Weekly Teaching Hours	TH : 03	Tut:		
Scheme of Marking	TH :60	Tests : 20	IA: 20	Total : 100

### **Course Objective:**

А	To impart knowledge on basics of MEMS and their applications in RF circuit design
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# **Course Outcomes:**

CO1	Learner will be able to understand the fundamentals of VLSI CAD
CO2	Learner will be able to understand the simulation and design of RTL
CO3	Learner will be able to demonstrate various verification methodologies
CO4	Learner will be able to analyze different fundamentals of Layout Synthesis
CO5	Learner will be able to design a system based on C and Verilog

# <u>UNIT I</u>

Introduction to VLSI CAD: Motivating factors and some trends; digital hardware modeling: logic and system level modeling, hardware description languages (VHDL and Verilog)

# <u>UNIT II</u>

RTL simulation; synchronous and asynchronous system design;

# <u>UNIT III</u>

Verification methodology: simulation, BDD, formal methods; logic synthesis: technology mapping, ASIC design methodology, FPGA based system design and prototyping;

# <u>UNIT IV</u>

Layout synthesis: the physical design, timing analysis; graph algorithms and their application in IC design;

# <u>UNIT V</u>

CAD tools and their use; Design for testability

# <u>UNIT VI</u>

System level design: brief mention of System C and System Verilog

# **TEXT/REFERENCE BOOKS**

1. S.H. Gerez, Algorithms for VLSI Design Automation, Wiley-India, 1999

2. Giovanni De Micheli, Synthesis and Optimization of Digital Circuits, Tata McGraw Hill, 1994

3. D.D Gajski et al., High Level Synthesis: Introduction to Chip and System Design, Kluwer Academic Publishers, 1992

4. N.A. Sherwani, Algorithms for VLSI Physical Design Autmation, Kluwer Academic Publisher

5.M. Sarrafzadeh and C.K. Wong, An Introduction to VLSI Physical Design, McGraw Hill, 1996

6.Current Literature: IEEE Trans. on CAD of ICs, IEEE Trans. on VLSI Systems, ACM TODAES

# ELECTIVE IV SEMICONDUCTOR MEMORY DESIGN AND TESTING

Weekly Teaching Hours	TH : 03	Tut:		
Scheme of Marking	TH :60	Tests : 20	IA: 20	Total : 100

**Course Objective:** 

А	Describing the structure and operation of the main types of semiconductor memory.
В	The different contexts in which memories are tested together with the corresponding different types of tests.

# **Course Outcomes:**

CO1	Learner will be able to understand memory cell structures and fabrication technologies.
CO2	Learner will be able to demonstrate application–specific memories and architectures.
CO3	Learner will be able to analyze memory design, fault modeling and test algorithms, limitations, and trade-offs
CO4	Learner will be able to analyze general reliability issues of memory.
CO5	Learner will be able to analyze various effects of radiation on memory

# <u>UNIT I</u>

**Random Access Memory Technologies:** SRAM – SRAM Cell structures, MOS SRAM Architecture, MOS SRAM cell and peripheral circuit operation, Bipolar SRAM technologies, SOI technology, Advanced SRAM architectures and technologies, Application specific SRAMs, DRAM – DRAM technology development, CMOS DRAM, DRAM cell theory and advanced cell structures, BICMOS DRAM, soft error failure in DRAM, Advanced DRAM design and architecture, Application specific DRAM

# <u>UNIT II</u>

**Non-volatile Memories:** Masked ROMs, High density ROM, PROM, Bipolar ROM, CMOS PROMS, EPROM, Floating gate EPROM cell, One time programmable EPROM, EEPROM, EEPROM technology and architecture, Non-volatile SRAM, Flash Memories (EPROM or EEPROM), advanced Flash memory architecture

# <u>UNIT III</u>

Memory Fault Modeling Testing and Memory Design for Testability and Fault Tolerance: RAM fault modeling, Electrical testing, Pseudo Random testing, Megabit DRAM Testing, non-volatile memory modeling and testing, IDDQ fault modeling and testing, Application specific memory testing, RAM fault modeling, BIST techniques for memory

# <u>UNIT IV</u>

**Semiconductor Memory Reliability:** General reliability issues RAM failure modes and mechanism, Non-volatile memory reliability, reliability modeling and failure rate prediction, Design for Reliability, Reliability Test Structures, Reliability Screening and qualification,

# <u>UNIT V</u>

# **Radiation Effects:**

Radiation effects, Single Event Phenomenon (SEP), Radiation Hardening techniques, Radiation Hardening Process and Design Issues, Radiation Hardened Memory characteristics, Radiation Hardness Assurance and Testing, Radiation Dosimetry, Water Level Radiation Testing and Test structures

# <u>UNIT VI</u>

Advanced Memory Technologies and High-density Memory Packing Technologies: Ferroelectric RAMs (FRAMs), GaAs FRAMs, Analog memories, magneto resistive RAMs (MRAMs), Experimental memory devices, Memory Hybrids and MCMs (2D), Memory Stacks and MCMs (3D), Memory MCM testing and reliability issues, Memory cards, High Density Memory Packaging Future Directions

# **TEXT/REFERENCE BOOKS**

1. Ashok K. Sharma, Semiconductor Memories Technology, 2002, Wiley.

2. Ashok K. Sharma, Advanced Semiconductor Memories - Architecture, Design and Applications 2002, Wiley.

3. Chenming C Hu ,Modern Semiconductor Devices for Integrated Circuits –, 1st Ed., Prentice Hall.

# <u>ELECTIVE IV</u> FPGA SYSTEM DESIGN

Weekly Teaching Hours	TH : 03	Tut:		
Scheme of Marking	TH :60	Tests : 20	IA: 20	Total : 100

### **Course Objective:**

Α	To introduce students to advanced design methodologies and practical design approaches for high - performance FPGA applications.
В	Design and implement a complete sophisticated digital system application on an FPGA.

# **Course Outcomes:**

CO1	Learner will be able to translate a software application into hardware logic for FPGA architectures
CO2	Learner will be able to understand design synthesizable VHDL systems based on industry - standard coding methods
CO3	Learner will be able to understand optimize logic for various performance goals (timing, frequency, area, and power).

# <u>Unit I</u>

Introduction to Asics, CMOS Logic and ASIC Library Design Types of ASICs - Design Flow - CMOS transistors, CMOS design rules - Combinational Logic Cell - Sequential logic cell -Data path logic cell - transistors as resistors - transistor parasitic capacitance - Logical effort -Library cell design - Library architecture

# <u>Unit II</u>

Programmable Logic Cells and I/O Cells Digital clock Managers-Clock management-Regional clocks- Block RAM – Distributed RAM Configurable Logic Blocks-LUT based structures – Phase locked loops- Select I/O resources –Anti fuse - static RAM - EPROM and EEPROM technology.

# <u>Unit III</u>

Device Architectures Device Architecture-Spartan 6 -Vertex 4 architecture- Altera Cyclone and Quartos architectures

# <u>Unit IV</u>

Design Entry and Testing Logic synthesis using HDL- Types of simulation –Faults- Fault simulation - Boundary scan test - Automatic test pattern generation. Built-in self-test. – scan test.

# <u>Unit V</u>

Floor Planning, Placement and Routing System partition - FPGA partitioning - partitioning methods - floor planning - placement

# <u>Unit VI</u>

Physical design flow - global routing - detailed routing - special routing - circuit extraction – DRC

# **TEXT/REFERENCE BOOKS**

1. M.J.S. SMITH, Application Specific Integrated Circuits, Pearson Education, 2006.

2. Ronald Sass and Andrew G. Schmidt, Embedded systems design with platform FPGAs:

Principles and practices, Morgan Kaufmann, 2010.

3. Design manuals of Altera, Xilinx and Actel.

# ELECTIVE IV NANOSCALE DEVICES AND CIRCUIT DESIGN

Weekly Teaching Hours	TH : 03	Tut:		
Scheme of Marking	TH :60	Tests: 20	IA: 20	Total : 100

**Course Objective:** 

А	To provide knowledge of device physics/operation, technologies and issues in nanoscale CMOS and other emerging devices.
В	Developing innovative circuit design and integration technologies using nanostructured materials
С	The student will have the knowledge of silicon technology scaling and trends
D	The student will have the knowledge of challenges of technology scaling in nano - scale regimes

# **Course Outcomes:**

CO1	Learner will be able to exploiting non - classical cmos devices for circuit Design in such technologies
CO2	Learner will be able to acquire knowledge of prospects of future non - silicon nanotechnologies
CO3	Learner will be able to acquire knowledge of challenges associated leakage currents and process variations
CO4	Learner will be able to develop a new design techniques under excessive Leakage and process variations

# <u>UNIT I</u>

CMOS scaling challenges in Nano scale regimes: Moor and Koomey's law, Leakage current mechanisms in Nano scale CMOS, leakage control and reduction techniques, process variations in devices and interconnects.

# <u>UNIT II</u>

Device and technologies for sub 100nm CMOS: Silicidation and Cu-low k interconnects, strain silicon – biaxial stain and process induced strain; Metal-high k gate;

# <u>UNIT III</u>

Emerging CMOS technologies at 32nm scale and beyond – FINFETs, surround gate nanowire MOSFETs, heterostructure (III-V) and Si-Ge MOSFETs.

# <u>UNIT IV</u>

Device scaling and ballistic MOSFET: Two dimensionalscaling theory of single and multigate MOSFETs, generalized scale length, quantum confinement and tunneling in

MOSFTEs, velocity saturation, carrier back scattering and injection velocity effects, scattering theory of MOSFETs

# UNIT V

Emerging Nano scale devices: Si and hetero-structure nanowire MOSFETs, carbon nanotube MOSFETs, Tunnel FET, quantum wells, quantum wires and quantum dots; Single electron transistors, resonant tunneling devices.

# <u>UNIT IV</u>

Non-classical CMOS: CMOS circuit design using non-classical devices – FINFETs, nanowire, carbon nanotubes and tunnel devices.

# **TEXT/REFERENCE BOOKS**

1. Lundstrom, M., Nanoscale Transport: Device Physics, Modeling, and Simulation, Springer.2005

2. Maiti, C.K., Chattopadhyay, S. and Bera, L.K., Strained-Si and Hetrostructure Field Effect Devices, Taylor and Francis.2007

3. Hanson, G.W., Fundamentals of Nanoelectronics, Pearson India. 2008

4. Wong, B.P., Mittal, A., Cao Y. and Starr, G., Nano-CMOS Circuit and Physical Design, Wiley. 2004

5. SandipKundu, AswinSreedhar, Nanoscale CMOS VLSICircuits: Design for Manufacturability McGraw Hill 2010

6. Research and Review papers in specific area

# **ELECTIVE-IV**

# ANALYSIS AND DESIGN OF DIGITAL SYSTEMS USING VHDL

Weekly Teaching Hours	TH : 03	Tut:		
Scheme of Marking	TH : 60	Tests: 20	IA: 20	Total : 100

### **Course Objective:**

А	To prepare the student to understand the VHDL language feature to realize the complex digital systems.
В	To design and simulate sequential and concurrent techniques in VHDL
С	To explain modeling of digital systems using VHDL and design methodology
D	To explain predefined attributes and configurations of VHDL.
Е	To Understand behavioral, non-synthesizable VHDL and its role in modern design

### **Course Outcomes:**

CO1	Learner will be able to demonstrate, simulate, verify, and synthesize with hardware description languages.
CO2	Learner will be able to understand and use major syntactic elements of VHDL - entities, architectures, processes, functions, common concurrent statements, and common sequential statements
CO3	Learner will be able to design digital logic circuits in different types of modeling
CO4	Learner will be able to demonstrate timing and resource usage associated with modeling approach.
CO5	Learner will be able to use computer-aided design tools for design of complex digital logic circuits.

# <u>UNIT I</u>

An overview of design procedures for system design using CAD tools. Design verification tools. Examples using commercial PC based VLSI CAD tools. Design methodology based on

VHDL. Basic concepts and structural descriptions in VHDL.

# <u>UNIT II</u>

Characterizing hardware languages, objects and classes, signal assignments, concurrent and sequential assignments. Structural specification of hardware.

# <u>UNIT III</u>

Design organization, parameterization and high level utilities, definition and usage of subprograms, packaging parts and utilities, design parameterization, design configuration, design libraries. Utilities for high-level descriptions.

# <u>UNIT IV</u>

Data flow and behavioral description in VHDL- multiplexing and data selection, state machine description, open collector gates, three state bussing, general dataflow circuit, updating basic utilities. Behavioral description of hardware.

# <u>UNIT V</u>

CPU modeling for discrete design- Parwan CPU, behavioral description, bussing structure, data flow, test bench, a more realistic Parwan.

# <u>UNIT VI</u>

Interface design and modeling. VHDL as a modeling language.

# **TEXTBOOKS / REFERENCE:**

- 1. Z.Navabi, "VHDL Analysis and Modeling of Digital Systems", (2/e), McGraw Hill
- 2. A. Dewey, "Analysis and Design of Digital Systems with VHDL", CL-Engineering
- 3. Z.Navabi,"VHDL: modular design and synthesis of cores and systems", McGraw
- 4. C. H. Roth, Jr., L.K.John, "Digital Systems Design Using VHDL Thomson Learning EMEA", Limited, 2008.
- 5. Recent literature in Analysis and Design of Digital Systems using VHDL.

# **ELECTIVE V**

# ASIC AND SOC

Weekly Teaching Hours	TH : 03	Tut:		
Scheme of Marking	TH :60	Tests : 20	IA: 20	Total : 100

### **Course Objective:**

А	Impart the knowledge and skills for RTL (Register Transfer Level) designing and netlist generation
В	The learning encompasses SOC designing and also focuses on HDL techniques for high performance designs intended for programmable logic devices.

# **Course Outcomes:**

CO1	Understand the fundamentals of logic designing and Analog/Mixed signal (AMS) IC designing
CO2	Perform ASIC verification
CO3	Conduct design Synthesis for ASIC methodologies
CO4	Demonstrate high performance designs using HDL techniques

# <u>Unit I</u>

**Types of ASICs** – Design flow – Economics of ASICs – ASIC cell libraries – CMOS logic cell data path logic cells – I/O cells – cell compilers.

# <u>Unit II</u>

**ASIC Library design:** Transistors as resistors – parasitic capacitance – logical effort programmable ASIC design software: Design system – logic synthesis – half gate ASIC, ASIC Construction – Floor planning & placement – Routing

# <u>Unit III</u>

**System on Chip Design Process:** A canonical SoC design, SoC Design Flow – Waterfall vs Spiral, Top-Down versus Bottom-Up. Specification requirements, Types of Specifications, System Design Process,

# <u>Unit IV</u>

**System level design issues-** Soft IP vs. Hard IP, Design for Timing Closure- Logic Design Issues, Physical Design Issues;

# <u>Unit V</u>

**Verification Strategy** On-Chip Buses and Interfaces; Low Power, Manufacturing Test Strategies. MPSoCs. Techniques for designing MPSoCs

# <u>Unit VI</u>

**SoC Verification**: Verification technology options, Verification methodology, Verification languages, Verification approaches, and Verification plans. System level verification, Block level verification, Hardware/software co-verification, and Static net list verification.

# **TEXT BOOKS / REFERENCE:**

1., Prakash Rashinkar, Peter Paterson and Leena Singh. Kluwer, SoC Verification-Methodology and Techniques, Academic Publishers, 2001.

2. Michael Keating, Pierre Bricaud, Kluwer, Reuse Methodology manual for System-On-A-Chip Designs Academic Publishers, second edition, 2001

3. Smith, Application Specific Integrated Circuits, Addison-Wesley, 2006

	ELEC	CTIVE V		
IC TECHNOLOGY				
Weekly Teaching Hours	TH:03	Tut:		
Scheme of Marking	TH :60	Tests : 20	IA: 20	Total : 100

### **Course Objectives:**

А	This course introduces students to the fundamentals of VLSI manufacturing
	processes and technology.

### **Course Outcome:**

CO1	To understand physics of the Crystal growth, wafer fabrication and basic properties of silicon wafers.
CO2	To learning lithography techniques and concepts of wafer exposure system, types of resists etc.
CO3	To understand concepts of thermal oxidation and Si/SiO2 interface and its quality measurements.
CO4	To learn concepts of thin film deposition including chemical Vapor Deposition and Physical vapor deposition.
CO5	To understand back-end technology to define contacts, interconnect, gates, source and drain, and measurement techniques to insure quality of designs.
CO6	To understand MOS and Bipolar Process Integration.

# <u>UNIT I</u>

# Introduction

Introduction to Semiconductor Manufacturing and fabrication. Physics of the Crystal growth, waferfabrication and basic properties of silicon wafers.

# <u>UNIT II</u>

# Lithography, Thermal Oxidation of Silicon:

The Photolithographic Process, Etching Techniques, Photomask Fabrication, Exposure Systems, Exposure sources, The Oxidation Process, Modeling Oxidation, Masking Properties of SiliconDioxide, Technology of Oxidation, Si-SiO2 Interface.

# <u>UNIT III</u>

# Diffusion, Ion Implantation Film Deposition:

The Diffusion Process, Mathematical Model for Diffusion, Constant-, The Diffusion Coefficient, Successive Diffusions, Diffusion Systems, Implantation Technology, Mathematical Model for Ion Implantation, Selective Implantation, Channeling, Lattice Damage and Annealing, Shallow Implantations, Chemical Vapor Deposition, Physical Vapor Deposition, Epitaxy.

# <u>UNIT IV</u>

Interconnections and Contacts, Packaging and Yield Metal Interconnections and Contact Technology, Diffused Interconnections, Polysilicon Interconnections and Buried Contacts, Silicides and Multilayer-Contact Technology, Copper Interconnects and Damascene Processes, Wafer Thinning and Die Separation, Die Attachment, Wire Bonding, Packages, Yield.

# <u>UNIT V</u>

MOS Process Integration, Bipolar Process Integration, Basic MOS Device Considerations, MOS Transistor Layout and Design Rules, ComplementaryMOS (CMOS) Technology, The Junction-Isolated Structure, Current Gain, Transit Time,Basewidth, Breakdown Voltages, Other Elements In SBC Technology

# <u>UNIT VI</u>

Advanced Bipolar Structures, Other Bipolar Isolation Techniques. Deep Submicron Processes, Low-Voltage/Low-PowerCMOS/BiCMOS Processes. Future Trends and Directions of CMOS/BiCMOS Processes.

# **TEXT BOOKS / REFERENCE:**

1. J. Plummer, Michael D. Deal and Peter B. Griffin, Silicon VLSI Technology, fundamentals, practice and modeling Pearson Education, 2009.

2. Richard C. Jaeger, Introduction to Microelectronic Fabrication, Second Edition.

3. C.Y. Chang and S. M. Sze, ULSI Technology, McGraw Hill 1996.

4. S.K. Ghandhi, VLSI Fabrication Principles, Wiley, 2nd edition 1994.

5. Stanley wolf, Silicon Processing for VLSI era, volume 4, Deep sub-micron process technology, Lattice Press, 1990.

# <u>Elective V</u> LINEAR ALGEBRA

Weekly Teaching Hours	TH : 03	Tut:		
Scheme of Marking	TH :60	Tests : 20	IA: 20	Total : 100

### **Course Objectives:**

А	To provide in-depth understanding of fundamental concepts of linear algebra
В	To understand the importance of linear algebra and learn its applicability to practical problems

# **Course Outcomes:**

CO1	Student will learn to solve and analyze linear system of equation
CO2	Student will analyze the direct notations, duality, adjointness, bases, dual bases in linear algebra
CO3	Student will understand the concept of Linear transformations and matrices, equivalence, similarity.
CO4	Student will be able to find eigen values and eigen vectors using characteristics polynomials
CO5	Student will learn to find the singular value decomposition of the matrix
CO6	Student will be to find the inverse of matrix

# <u>UNIT I</u>

Fields Fq, R, C. Vector Spaces over a field, Fn, F[ $\theta$ ]=Polynomials in one Variable.

# <u>UNIT II</u>

Direct Notations, Ket, bra vector, duality, adjointness, linear transformations, bases, dual bases.

# <u>UNIT III</u>

Linear transformations and matrices, equivalence, similarity.

# UNIT IV

Eigenvalues, eigenvectors, diagonalization, Jordoncanonical form

# <u>UNIT V</u>

Bilinear and sesquilinear forms, inner product, orthonormal, bases, orthogonal decomposition, projections

# <u>UNIT VI</u>

System of equations, generalized inverses.

### **TEXT BOOKS / REFERENCE:**

1. Ronald Shaw, Linear Algebra and Group Representations, AcademicPress, Volume I-1982.

2. Ronald Shaw, Linear Algebra and Group Representations, AcademicPress, Volume II-1983.

3. A. R. Rao, BhimaSankaran, Linear Algebra, TRIM, 2nd Edition, Hindustan

# <u>ELECTIVE V</u> RESEARCH METHODOLOGY

Weekly Teaching Hours	TH:03	Tut:		
Scheme of Marking	TH :60	Tests : 20	IA: 20	Total : 100

# **Course Objectives:**

А	To develop a research orientation among the scholars and to acquaint them with fundamentals of research methods.
В	To develop understanding of the basic framework of research process.
С	To identify various sources of information for literature review and data collection.
D	To understand the components of scholarly writing and evaluate its quality.

### **Course Outcomes:**

CO1	Student will learn the meaning, objective, motivation and type of research
CO2	Student will be able to formulate their research work with the help of literature review
CO3	Student will be able to develop an understanding of various research design and techniques
CO4	Student will have an overview knowledge of modeling and simulation of research work
CO5	Student will be able to collect the statistical data with different methods related to research work
CO6	Student will be able to write their own research work with ethics and non-plagiarized way

# <u>UNIT I</u>

Introduction: Defining research, Motivation and Course Objective:s, Types of research

Meaning of Research, Course Objective:s of Research, Motivation in Research, Types of Research

# <u>UNIT II</u>

Research Formulation: Formulating The research Problem, Literature Review, Development of Working Hypothesis

# <u>UNIT III</u>

Research Design: Important Concept in Research Design, Research Life Cycle, Developing Research Plan

# <u>UNIT IV</u>

Overview of Modeling and Simulation: Classification of models, Development of Models, Experimentation, Simulation.

# <u>UNIT V</u>

Statistical Aspects: Methods of Data Collection, Sampling Methods, Statistical analysis, Hypothesis testing.

# <u>UNIT VI</u>

Research Report: Research Ethics, Plagiarism, Research Proposal, Report Writing and Writing Research Papers.

# **TEXT BOOKS / REFERENCE:**

- 1. J.P. Holman. ,Experimental Methods for Engineers
- 2. C.R. Kothari, Research Methodology, Methods & Techniques

# ELECTIVE VINTERNET OF THINGSWeekly Teaching HoursTH : 03Tut: --Scheme of MarkingTH : 60Tests : 20IA: 20Total : 100

# **Course Objectives:**

А	Students will be explored to the interconnection and integration of the physical world
	and the cyber space.
В	To provide ability to design and develop IOT devices.

# **Course Outcomes:**

CO1	Learner will be able to understand the meaning of internet in general and IOT in terms
	of layers, protocols, packets peer to peer communication
CO2	Learner will be able to interpret IOT working at transport layer with the help of various
	protocols
CO3	Learner will be able to understand IOT concept at data link layer
CO4	Learner will be able to apply the concept of mobile networking to the internet
	connected devices
CO5	Learner will be able to measure and schedule the performance of networked devices in
	IOT
CO6	Learner will be able to analyze the challenges involve in developing IOT architecture

# <u>UNIT I</u>

Introduction: What is the Internet of Things: History of IoT, about objects/things in the IoT, Overview and motivations, Examples of applications, IoT definitions, IoT Frame work, General observations, ITU-T views, working definitions, and basic nodal capabilities.

# <u>UNIT II</u>

Fundamental IoT Mechanisms & Key Technologies : Identification of IoT objects and services, Structural aspects of the IoT, Environment characteristics, Traffic characteristics ,scalability, Interoperability, Security and Privacy, Open architecture, Key IoT Technologies ,Device Intelligence, Communication capabilities, Mobility support, Device Power, Sensor Technology, RFID technology, Satellite Technology.

# <u>UNIT III</u>

Radio Frequency Identification Technology: Introduction, Principles of RFID, Components of an RFID system, Reader, RFID tags, RFID middleware, Issue. Wireless Sensor Networks: History and context, node, connecting nodes, networking nodes, securing communication. <u>UNIT IV</u>

Wireless Technologies For IoT : Layer <sup>1</sup>/<sub>2</sub> Connectivity : WPAN Technologies for IoT/M2M, Zigbee /IEEE 802.15.4, Radio Frequency for consumer Electronics (RF4CE), Bluetooth and

its low-energy profile, IEEE 802.15.6 WBANS, IEEE 802.15 WPAN TG4j, MBANS, NFC, dedicated short range communication( DSRC) & related protocols. Comparison of WPAN technologies cellular & mobile network technologies for IoT/M2M.

# <u>UNIT V</u>

Governance of The Internet of Things: Introduction, Notion of governance, aspects of governance, Aspects of governance Bodies subject to governing principles, private organizations, International regulation and supervisor, substantive principles for IoT governance, Legitimacy and inclusion of stakeholders, transparency, accountability. IoT infrastructure governance, robustness, availability, reliability, interoperability, access. Future governance issues, practical implications, legal implications.

# <u>UNIT VI</u>

Internet of Things Application Examples: Smart Metering, advanced metering infrastructure, e-Health/Body area network, City automation, automotive applications. Home automation, smart cards, Tracking, Over-The-Air passive surveillance/Ring of steel, Control application examples.

# **TEXTBOOKS / REFERENCE:**

- 1. Hakima Chaouchi, The Internet of Things, Connecting Objects to the Web, Wiley Publications
- 2. Daniel Minoli,Building the Internet of Things with IPv6 and MIPv6 The Evolving World of M2M Communications, Wiley Publications
- 3. Bernd Scholz-Reiter, Florian Michahelles, Architecting the Internet of Things, ISBN 978- 3842-19156-5, Springer.
- 4. Olivier Hersent, David Boswarthick, Omar Elloumi, The Internet of Things Key Applications and Protocols, ISBN 978-1-119-99435-0, Wiley Publications.

### **SEMINAR I**

Weekly Teaching Hours	TH: -	Practical: 04	
Scheme of Marking	IA: 50	PR/OR: 50	Total: 100

The seminar shall be on the state of the art in the area of the wireless communication and computing and of student's choice approved by an authority. The student shall submit the duly certified seminar report in standard format, for satisfactory completion of the work duly signed by the concerned guide and head of the Department/Institute.

### **MINI PROJECT**

Weekly Teaching Hours	TH: -	Practical: 04	
Scheme of Marking	IA: 50	PR/OR: 50	Total: 100

The mini project shall be based on the recent trends in the industry, research and open problems from the industry and society. This may include mathematical analysis, modelling, simulation, and hardware implementation of the problem identified. The mini project shall be of the student's choice and approved by the guide. The student has to submit the report of the work carried out in the prescribed format signed by the guide and head of the department/institute.

# PROJECT MANAGEMENT AND INTELLECTUAL PROPERTY RIGHTS

Weekly Teaching Hours	TH: -	Practical: -	
Scheme of Marking	IA: 50	PR/OR: 50	Total: 100

The Student has to choose this course either from NPTEL/MOOCs/SWAYAM pool. It is mandatory to get the certification of the prescribed course.

<b>PROJECT-I</b>
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Weekly Teaching Hours	TH: -	Practical: -	
Scheme of Marking	IA: 50	PR/OR: 50	Total: 100

Project-I is an integral part of the final project work. In this, the student shall complete the partial work of the project which will consist of problem statement, literature review, project overview, scheme of implementation that may include mathematical model/SRS/UML/ERD/block diagram/ PERT chart, and layout and design of the proposed system/work. As a part of the progress report of project-I work, the candidate shall deliver a presentation on progress of the work on the selected dissertation topic.

It is desired to publish the paper on the state of the art on the chosen topic in international conference/ journal.

The student shall submit the duly certified progress report of project -I in standard format for satisfactory completion of the work duly signed by the concerned guide and head of the department/institute.
## **PROJECT-II**

Weekly Teaching Hours	TH: -	Practical: -	
Scheme of Marking	IA: 100	PR/OR: 100	Total: 200

In Project - II, the student shall complete the remaining part of the project which will consist of the simulation/ analysis/ synthesis/ implementation / fabrication of the proposed project work, work station, conducting experiments and taking results, analysis and validation of results and drawing conclusions.

It is mandatory to publish the paper on the state of the art on the chosen topic in international conference/ journal.

The student shall prepare the duly certified final report of project work in standard format for satisfactory completion of the work duly signed by the concerned guide and head of the department/institute.